Unit: mm

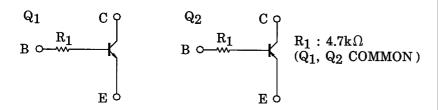
TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process) Silicon PNP Epitaxial Type (PCT Process)

# **RN4990**

# Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

- Includeing two devices in US6 (ultra super mini type with 6 leads)
- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process

#### **Equivalent Circuit and Bias Resister Values**



#### Q1 Maximum Ratings (Ta = 25°C)

| Characteristic            | Symbol         | Rating | Unit |
|---------------------------|----------------|--------|------|
| Collector-base voltage    | $V_{CBO}$      | 50     | V    |
| Collector-emitter voltage | $V_{CEO}$      | 50     | V    |
| Emitter-base voltage      | $V_{EBO}$      | 5      | V    |
| Collector current         | I <sub>C</sub> | 100    | mA   |

### 2.1 ± 0.1 1.25 ± 0.1 1. EMITTER 1 (E1) BASE 1 (B1) **COLLECTOR 2** (C2) EMITTER 2 (E2) BASE 2 (B2) US6 **COLLECTOR 1** (C1) **JEDEC** EIAJ TOSHIBA 2-2J1A

Weight: 6.8mg

#### Q2 Maximum Ratings (Ta = 25°C)

| Characteristic            | Symbol           | Rating | Unit |
|---------------------------|------------------|--------|------|
| Collector-base voltage    | V <sub>CBO</sub> | -50    | V    |
| Collector-emitter voltage | V <sub>CEO</sub> | -50    | ٧    |
| Emitter-base voltage      | V <sub>EBO</sub> | -5     | ٧    |
| Collector current         | Ic               | -100   | mA   |

## Q1, Q2 Common Maximum Ratings (Ta = 25°C)

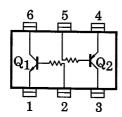
| Characteristic              | Symbol           | Rating  | Unit |
|-----------------------------|------------------|---------|------|
| Collector power dissipation | P <sub>C</sub> * | 200     | mW   |
| Junction temperature        | Tj               | 150     | °C   |
| Storage temperature range   | T <sub>stg</sub> | -55~150 | °C   |

<sup>\* :</sup> Total rating

## Marking



## **Equivalent Circuit (Top View)**



## Q1 Electrical Characteristics (Ta = 25°C)

| Characteristic                       | Symbol                | Test<br>Circuit | Test Condition                                       | Min | Тур. | Max | Unit |
|--------------------------------------|-----------------------|-----------------|--|-----|------|-----|------|
| Collector cut-off current            | I <sub>CBO</sub>      | _               | V <sub>CB</sub> = 50V, I <sub>E</sub> = 0            | _   | _    | 100 | mA   |
| Emitter cut-off current              | I <sub>EBO</sub>      | _               | V <sub>EB</sub> = 10V, I <sub>C</sub> = 0            | 1   | -    | 100 | mA   |
| DC current gain                      | h <sub>FE</sub>       | _               | V <sub>CE</sub> = 5V, I <sub>C</sub> = 1mA           | 120 | _    | 700 | _    |
| Collector-emitter saturation voltage | V <sub>CE (sat)</sub> | _               | I <sub>C</sub> = 5mA, I <sub>B</sub> = 0.25mA        | _   | 0.1  | 0.3 | V    |
| Transition frequency                 | f <sub>T</sub>        | _               | V <sub>CE</sub> = 10V, I <sub>C</sub> = 5mA          | _   | 250  | _   | MHz  |
| Collector output capacitance         | C <sub>ob</sub>       | _               | V <sub>CB</sub> = 10V, I <sub>E</sub> = 0, f = 1 MHz | _   | 3    | 6   | pF   |

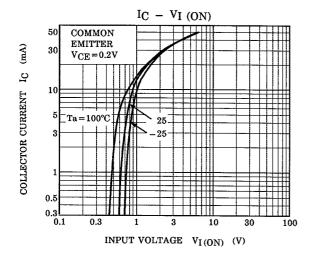
### **Q2 Electrical Characteristics (Ta = 25°C)**

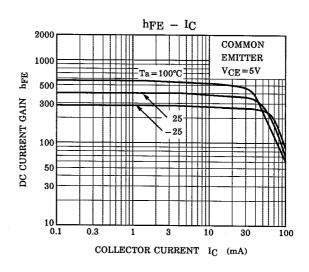
| Characteristic                       | Symbol                | Test<br>Circuit | Test Condition                                       | Min | Тур. | Max  | Unit |
|--------------------------------------|-----------------------|-----------------|--|-----|------|------|------|
| Collector cut-off current            | I <sub>CBO</sub>      | _               | $V_{CB} = -50V, I_E = 0$                             | _   | _    | -100 | mA   |
| Emitter cut-off current              | I <sub>EBO</sub>      | _               | $V_{EB} = -5V$ , $I_C = 0$                           | _   | _    | -100 | mA   |
| DC current gain                      | h <sub>FE</sub>       | _               | $V_{CE} = -5V$ , $I_C = -1mA$                        | 120 | _    | 400  | -    |
| Collector-emitter saturation voltage | V <sub>CE (sat)</sub> | _               | $I_C = -5mA$ , $I_B = -0.25mA$                       | _   | -0.1 | -0.3 | V    |
| Transition frequency                 | f <sub>T</sub>        | _               | $V_{CE} = -10V, I_{C} = -5mA$                        | _   | 200  | _    | MHz  |
| Collector output capacitance         | C <sub>ob</sub>       | _               | V <sub>CB</sub> = -10V, I <sub>E</sub> = 0, f = 1MHz | _   | 3    | 6    | pF   |

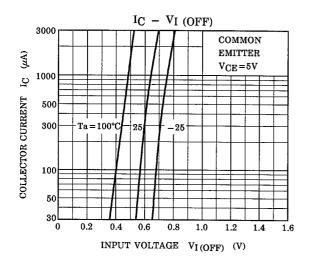
## Q1, Q2 Common Electrical Characteristics (Ta = 25°C)

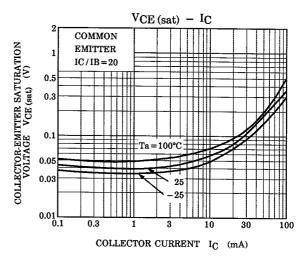
| Characteristic | Symbol | Test<br>Circuit | Test Condition | Min  | Тур. | Max  | Unit |
|----------------|--------|-----------------|----------------|------|------|------|------|
| Input resistor | R1     | _               | _              | 3.29 | 4.7  | 6.11 | kΩ   |

 $Q_1$ 

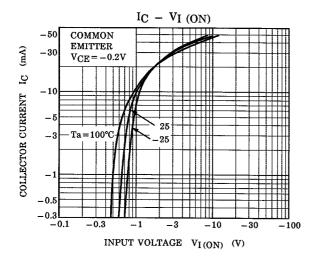


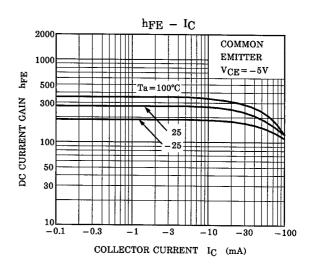


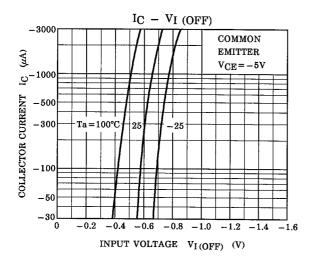


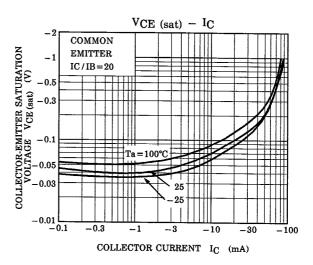


 $Q_2$ 









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